

## **SGA-2163(Z)**

# DC to 5000 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

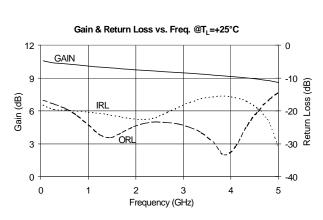
RFMD Green, RoHS Compliant, Pb-Free (Z Part Number)
Package: SOT-363



### **Product Description**

The SGA-2163 is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high  $F_T$  and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.





#### **Features**

- Broadband Operation: DC to 5000 MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

### **Applications**

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Parameter	Specification			Unit	Condition	
rarameter	Min.	Тур.	Max.	Onit	Condition	
Small Signal Gain	9.5	10.5	11.5	dB	850MHz	
		9.8		dB	1950MHz	
		9.6		dB	2400MHz	
Output Power at 1dB Compression		7.1		dBm	850MHz	
		6.2		dBm	1950MHz	
Output Third Intercept Point		21.0		dBm	850MHz	
		18.0		dBm	1950MHz	
Bandwidth Determined by Return Loss		5000		MHz	>10dB	
Input Return Loss		22.5		dB	1950MHz	
Output Return Loss		24.8		dB	1950 MHz	
Noise Figure		4.4		dB	1950MHz	
Device Operating Voltage	1.9	2.2	2.5	V		
Device Operating Current	17	20	23	mA		
Thermal Resistance		255		°C/W	junction - lead	

Test Conditions:  $V_S = 5V$ ,  $I_D = 20$  mA Typ.,  $OIP_3$  Tone Spacing = 1MHz,  $P_{OLIT}$  per tone = -10 dBm,  $R_{BIAS} = 140\Omega$ ,  $T_L = 25$  °C,  $Z_S = Z_L = 50\Omega$ 

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#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Max Device Current (I <sub>D</sub> )	40	mA
Max Device Voltage (V <sub>D</sub> )	4	V
Max RF Input Power	+18	dBm
Max Junction Temperature (T <sub>J</sub> )	+150	°C
Operating Temperature Range (T <sub>L</sub> )	-40 to +85	°C
Max Storage Temperature	+150	°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:  $I_DV_D < (T_J - T_L)/R_{TH}, j - I_J$ 



#### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

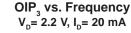
RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

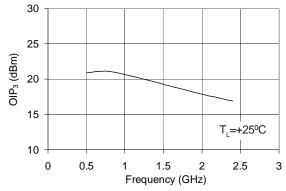
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Typical Performance at Key Operating Frequencies

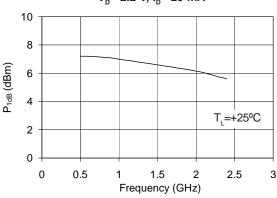
<u>, , , , , , , , , , , , , , , , , , , </u>							
Parameter	Unit	100 MHz	500MHz	850MHz	1950MHz	2400 MHz	3500 MHz
Small Signal Gain	dB	10.7	10.6	10.5	9.8	9.6	9.3
Output Third Order Intercept Point	dBm		20.9	21.0	18.0	16.9	
Output Power at 1dB Compression	dBm		7.2	7.1	6.2	5.6	
Input Return Loss	dB	18.7	19.8	20.3	22.5	22.1	16.0
Output Return Loss	dB	17.2	19.1	22.3	24.8	23.4	27.6
Reverse Isolation	dB	15.6	15.4	15.5	16.1	16.4	16.9
Noise Figure	dB		4.2	4.1	4.4	4.8	

 $Test\ Conditions: V_S=5V,\ I_D=20\ mA\ Typ.,\ OIP_3\ Tone\ Spacing=1\ MHz,\ P_{OUT}\ per\ tone=-10\ dBm,\ R_{BIAS}=140\ \Omega,\ T_L=25\ ^\circ C,\ Z_S=Z_L=50\ \Omega$ 

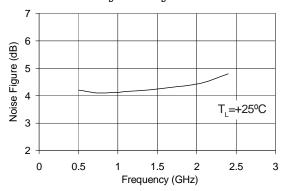




# $P_{1dB}$ vs. Frequency $V_D = 2.2 \text{ V}, I_D = 20 \text{ mA}$

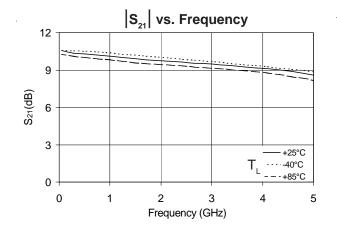


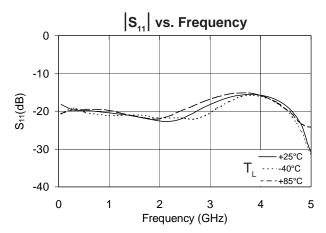
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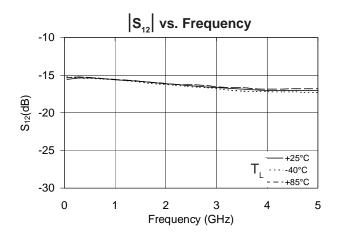


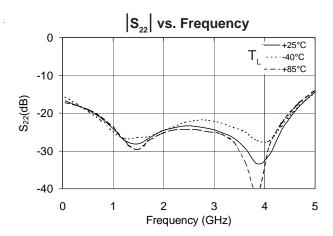


### Typical RF Performance Over Temperature (Bias: V<sub>D</sub>=2.2V, I<sub>D</sub>=20 mA (Typ.))





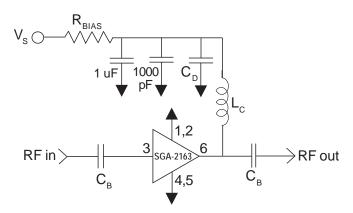


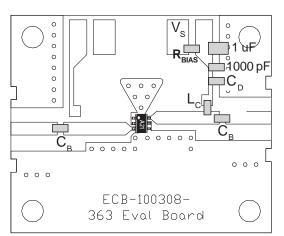


Pin	Function	Description
3	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
1, 2,	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
4, 5		
6	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.



## **Basic Application Circuit**





### **Application Circuit Element Values**

Reference	Frequency (Mhz)						
Designator	500	850	1950	2400	3500		
C <sub>B</sub>	220 pF	100 pF	68 pF	56 pF	39 pF		
C <sub>D</sub>	100 pF	68 pF	22 pF	22 pF	15 pF		
L <sub>c</sub>	68 nH	33 nH	22 nH	18 nH	15 nH		

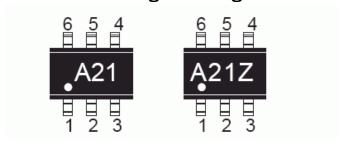
Recommended Bias Resistor Values for $I_D=20$ mA $R_{BIAS}=(V_S-V_D)/I_D$				
Supply Voltage(V <sub>S</sub> )	5 V	6 V	8 V	10 V
R <sub>BIAS</sub>	140Ω	200Ω	300Ω	390 Ω
Note: R <sub>BIAS</sub> provides DC bias stability over temperature.				

### **Mounting Instructions**

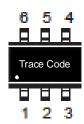
- Use a large ground pad area near device pins 1, 2,
   and 5 with many plated through-holes as shown.
- We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.



## **Package Drawing.**



## **Alternate Marking with Trace Code Only**



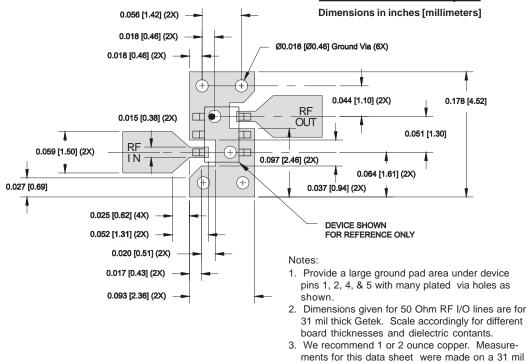
### **Ordering Information**

Part Number	Reel Size	Devices/Reel
SGA-2163	7"	3000
SGA-2163Z	7"	3000

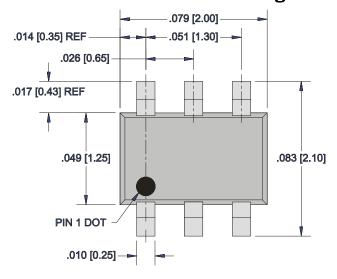


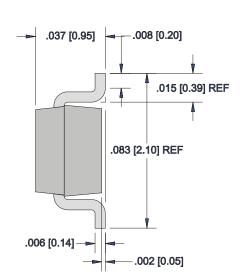
### **SOT-363 PCB Pad Layout**

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### **Package Dimensions**





thick Getek with 1 ounce copper on both sides.